NSN 5962-01-026-0495



Memory Microcircuit - Page 1 of 1 View Online at https://aerobasegroup.com/nsn/5962-01-026-0495 **Body Length:** Between 0.735 inches and 0.830 inches **Body Width:** Between 0.245 inches and 0.295 inches **Body Height:** 0.160 inches **Maximum Power Dissipation Rating:** 512.0 milliwatts **Operating Tempurature Range:** -65.0/+125.0 degrees celsius Storage Tempurature Range: -65.0/+160.0 degrees celsius **Features Provided:** Hermetically sealed and expandable and programmable and schottky and bipolar and high speed and w/open collector **Inclosure Material:** Ceramic and metal **Inclosure Configuration:** Dual-in-line **Output Logic Form:** Transistor-transistor logic **Input Circuit Pattern:** 10 input **Terminal Surface Treatment:** Solder Voltage Rating And Type Per Characteristic: -1.0 volts power source and 5.5 volts power source **Time Rating Per Chacteristic:** 70.00 nanoseconds propagation delay time, low to high level output **Memory Device Type:** Rom **Memory Capacity:** Unknown **Terminal Type And Quantity:**

16 printed circuit

Shelf Life:

N/a

Unit Of Measure:

--

Demilitarization:

Yes - demil/mli

Fiig:

A458a0